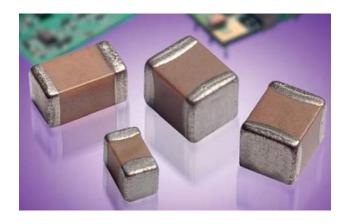
### X7R Dielectric

### **General Specifications**



RoHS



X7R formulations are called "temperature stable" ceramics and fall into EIA Class II materials. X7R is the most popular of these intermediate dielectric constant materials. Its temperature variation of capacitance is within ±15% from -55°C to +125°C. This capacitance change is non-linear.

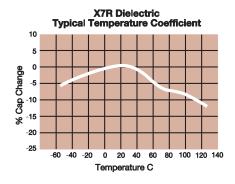
Capacitance for X7R varies under the influence of electrical operating con-ditions such as voltage and frequency.

X7R dielectric chip usage covers the broad spectrum of industrial applications where known changes in capacitance due to applied voltages are acceptable.

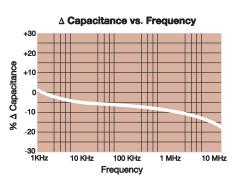
### PART NUMBER (see page 2 for complete part number explanation)

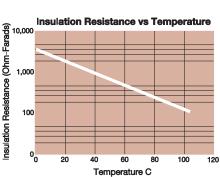
0805	<u>5</u>	<u>C</u>	103	<u>M</u>	<u>A</u>	<u>T</u>	<u>2</u>	A
Size (L" x W")	Voltage 4V = 4 6.3V = 6 10V = Z 16V = Y 25V = 3 50V = 5 100V = 1 200V = 2 500V = 7	<b>Dielectric</b> X7R = C		Capacitance Tolerance J = ± 5%* K = ±10% M = ± 20%  *≤1µF only, contact factory for additional values		Terminations T = Plated Ni and Sn 7 = Gold Plated* Z= FLEXITERM®**  *Optional termination  **See FLEXITERM® X7R section	Packaging 2 = 7" Reel 4 = 13" Reel Contact Factory For Multiples	Special Code A = Std. Product

NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.

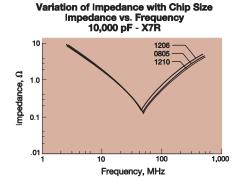


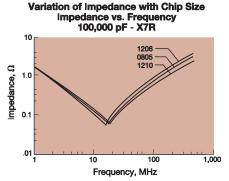
variation of impedance with Cap Value





Impedance vs. Frequency 1,000 pF vs. 10,000 pF - X7R 0805 10.00 pF 10,000 pF 10,000 pF 10,000 pF





# **X7R Dielectric**



## **Specifications and Test Methods**

Parame	eter/Test	X7R Specification Limits	Measuring Conditions								
Operating Tem	perature Range	-55°C to +125°C	Temperature Cy	cle Chamber							
Сарас	citance	Within specified tolerance	Freg : 1.0 kl	Hz + 10%							
Dissipati	on Factor	≤ 10% for ≥ 50V DC rating≤ 12.5% for 25V DC rating ≤ 12.5% for 25V and 16V DC rating ≤ 12.5% for ≤ 10V DC rating	Voltage: 1.0' For Cap > 10μF, (	√rms ± .2V							
Insulation	Resistance	100,000MΩ or 1000MΩ - $\mu$ F, whichever is less	Charge device with 120 ± 5 secs @ roo	•							
Dielectric	Strength	No breakdown or visual defects	Charge device with 250% of rated voltage for 1-5 seconds, w/charge and discharge current limited to 50 mA (max)  Note: Charge device with 150% of rated voltage for 500V devices.								
	Appearance	No defects	Deflection								
Resistance to	Capacitance Variation	≤ ±12%	Test Time: 3	0 seconds 7 1mm/sec							
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)									
	Insulation Resistance	≥ Initial Value x 0.3	Temperature Cy  Freq.: 1.0 k Voltage: 1.0' For Cap > 10µF, 0'  Charge device with 120 ± 5 secs @ ror  Charge device with 250 1-5 seconds, w/charge limited to 50 Note: Charge device voltage for 50 Deflection Test Time: 3  Dip device in eutectic for 5.0 ± 0.3  Dip device in eutectic solde Store at room temperature measuring electr  Step 1: -55°C ± 2° Step 2: Room Temp  Step 3: +125°C ± 2° Step 4: Room Temp  Repeat for 5 cycles 24 ± 2 hours at ro  Charge device with 1.5 r test chamber set at 125° (+48,  If RV > 10V then Life Test but there are exceptions of further details of the second	mm —							
Solde	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.5								
	Appearance	No defects, <25% leaching of either end terminal	_								
	Capacitance Variation	≤ ±7.5%	Dip device in eutectic solde	r at 260°C for 60seconds.							
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Store at room temperature for 24 ± 2hours before measuring electrical properties.								
	Insulation Resistance	Meets Initial Values (As Above)									
	Dielectric Strength	Meets Initial Values (As Above)									
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes							
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes							
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes							
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes							
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles at 24 ± 2 hours at ro								
	Appearance	No visual defects	Charge device with 1.5 rs	ated voltage (≲ 10V) in							
	Capacitance Variation	≤ ±12.5%	Charge device with 1.5 rated voltage (≤ 10V) in test chamber set at 125°C ± 2°C for 1000 hours (+48, -0)								
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	If RV > 10V then Life Tes								
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	further details o	n exceptions)							
	Dielectric Strength	Meets Initial Values (As Above)	Remove from test chamber temperature for 24 ± 2 ho								
	Appearance	No visual defects	Store in a test chambe	er set at 85°C + 2°C/							
	Capacitance Variation	≤ ±12.5%	85% ± 5% relative hun	nidity for 1000 hours							
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (See Above)									
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	temperature and	d humidity for							
	Dielectric Strength	Meets Initial Values (As Above)	2122 115413 5614								

# X7R Dielectric Capacitance Range



### PREFERRED SIZES ARE SHADED

SIZE	0101*			0201					0402	2					0603	}			0805							1206							
Soldering	Reflow Only		Ref	low C	Only		Reflow/Wave					Reflow/Wave					Reflow/Wave						Reflow/Wave										
Packaging	Paper/Embossed		Al	l Pap	er		All Paper					All Paper					Paper/Embossed							Paper/Embossed									
(L) Length mm	0.40 ± 0.02 (0.016 ± 0.0008)			0 ± 0		)	1.00 ± 0.10 (0.040 ± 0.004)					1.60 ± 0.15 (0.063 ± 0.006)						2.01 ± 0.20 (0.079 ± 0.008)							3.20 ± 0.20 (0.126 ± 0.008)								
(W) Width mm (in)	0.20 ± 0.02 (0.008 ± 0.0008)			0 ± 0 1 ± 0		)	0.50 ± 0.10 (0.020 ± 0.004)					0.81 ± 0.15 (0.032 ± 0.006)					1.25 ± 0.20 (0.049 ± 0.008)							1.60 ± 0.20 (0.063 ± 0.008)									
(t) Terminal mm (in)	0.10± 0.04 (0.004 ± 0.0016)			5 ± 0 6 ± 0		)			25 ± 0	).15 ).006)	)		(		5 ± 0 4 ± 0		i)		0.50 ± 0.25 (0.020 ± 0.010)							0.50 ± 0.25 (0.020 ± 0.010)							
WVDC	16	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	500
Cap 100 101	В	Α	Α	Α	Α	Α			С	С	С					G	G	G															
(pF) 150 151	В	Α	Α	Α	Α	Α			С	С	С					G	G	G															
220 221	В	Α	Α	Α	Α	Α			С	С	С					G	G	G	Е	Е	Е	Е	Е	Е	Е								
330 331	В	Α	Α	Α	Α	Α			С	С	С					G	G	G		J	J	J	J	J	J								K
470 471	В	Α	Α	Α	Α	Α			С	С	С					G	G	G		J	J	J	J	J	J								K
680 681	В	Α	Α	Α	Α				С	С	С					G	G	G		J	J	J	J	J	J								K
1000 102	В	Α	Α	Α	Α			С	С	С	С					G	G	G		J	J	J	J	J	J								K
1500 152	В	Α	Α	Α	Α		П	С	С	С	С		П	П		G	G			J	J	J	J	J	J		J	J	J	J	J	J	М
2200 222	В	Α	Α	Α	Α		П	С	С	С	С		П	П		G	G			J	J	J	J	J	J		J	J	J	J	J	J	М
3300 332		Α	Α	Α	Α			С	С	С	С					G	G			J	J	J	J	J	J		J	J	J	J	J	J	М
4700 472		Α	Α	Α	Α			С	С	С	С					G	G			J	J	J	J	J	J		J	J	J	J	J	J	М
6800 682		Α	Α	Α	Α		П	С	С	С	С		П	П		G	G			J	J	J	J	J	J		J	J	J	J	J	J	Р
Cap 0.01 103		Α	Α	Α	Α			С	С	С	С				G	G	G	J		J	J	J	J	J	J		J	J	J	J	J	J	Р
(µF) 0.015 153							П	С	С	С	С		П	$\Box$	G	G	G	J		J	J	J	J	J	J		J	J	J	J	J	М	Q
0.022 223								С	С	С	С				G	G	G			J	J	J	J	J	N		J	J	J	J	J	М	Q
0.033 333								С	С	С	С				G	G	J			J	J	J	J	N	N		J	J	J	J	J	М	Q
0.047 473								С	С	С	С		П	G	G	G	J			J	J	J	J	N	N		J	J	J	J	J	М	
0.068 683								С	С	С	С			G	G	G	J			J	J	J	J	N	N		J	J	J	J	J	Р	
0.1 104								С	С	С	С		G	G	G	G	J			J	J	J	J	N	N		J	J	J	J	Р	Р	
0.15 154						İ	$\vdash$					G	G	G	G					J	J	J	N	N			J	J	J	J	Q		
0.22 224						İ	$\vdash$	С	С	С		G	G	J	J	J				J	J	N	N	N		İ	J	J	J	J	Q		$\vdash$
0.33 334							$\vdash$					J	J	J	J					N	N	N	N	N			J	J	М	Р	Q		$\vdash$
0.47 474							С	С			$\vdash$	J	J	J	J	J				N	N	N	N	N			М	М	М	Р	Q		$\vdash$
0.68 684						m					$\vdash$	J	J	J						N	N	N				İ	М	М					
1.0 105					i –	t –	С			i –		J	J	J	J	J				N	N	N	N			İ	М	М		t	$\vdash$	$\vdash$	
2.2 225					i	i –				i –	<del>                                     </del>	J	J	J						P	Р	P	P**			İ	Q	Q	Q	Q	Q**		
4.7 475						i –						J								P	P	P					Q	Q	Q	Q			
10 106							$\vdash$		$\vdash$	<u> </u>	$\vdash$			Н	М				Р	P	P						ā	ã	X	X		$\vdash$	$\vdash$
22 226					$\vdash$		$\vdash$			$\vdash$	$\vdash$	t	М	Н	$\vdash$							$\vdash$	$\vdash$		$\vdash$	Q	Q	à			$\vdash$	$\vdash$	$\vdash$
47 476			$\vdash$				$\vdash$		$\vdash$	T	$\vdash$	t	М	Н						$\vdash$		$\vdash$	$\vdash$			Q	Q	X		t	$\vdash$	$\vdash$	$\vdash$
100 107			$\vdash$		$\vdash$		$\vdash$	$\vdash$	$\vdash$		$\vdash$	$\vdash$	М	Н	$\vdash$			$\vdash$		$\vdash$		$\vdash$	$\vdash$	$\vdash$		_	m			t	$\vdash$	$\vdash$	$\vdash$
WVDC	16	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	500
SIZE	0101		_	0201					0402						0603							0805				1206							

Letter	А	В	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z			
Max.	0.33	0.22	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79			
Thickness	(0.013)	(0.009)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)			
			PAF	PER			EMBOSSED										

NOTE: Contact factory for non-specified capacitance values

<sup>\*</sup>EIA 0100

<sup>\*\*</sup>Contact Factory for Specifications

## **X7R Dielectric**



### **Capacitance Range**

### PREFERRED SIZES ARE SHADED

	SIZE			1210							1812										222	0			2225	5			
	Solderin	na			Re	eflow C	nlv			Reflow Only						R	eflow C	nly	Reflow Only						eflow (	Only			
	Packagi						ossed			All Embossed							Embos				Embos		ssed						
		mm				3.30 ± (				4.50 ± 0.30							$.50 \pm 0.3$				.70 ± 0.				.25				
(L) Ler	igtn	(in.)				.130± 0				(0.177 ± 0.012)							177 ± 0.0				225 ± 0.				.010)				
(W) W	idth	mm (in.)				2.50 ± 0							± 0.20				.40 ± 0.4				.00 ± 0.				.25				
		mm	_			$0.098 \pm 0$							± 0.008	3)		_	252 ± 0.0 .61 ± 0.3				197 ± 0. .64 ± 0.			_	.010)				
(t) Terr	minal	(in.)				$.020 \pm 0$							± 0.014	1)			024 ± 0.0				0.04 ± 0.000.000000000000000000000000000				0.64 ± 0. .025 ± 0.				
	V	VVDC	10	16	25	50 100 200 500			16 25 50			100	200	500	50 100		200	25 50 100			200	500	50	100	200				
Сар	100	101	1																		I	1			1	' _			
(pF)	150	151	-																			>	*	$\checkmark$	W				
	220 330	221 331	+												_	$\vdash$				_				$\overline{}$	$\searrow \checkmark$				
	470	471	+													$\vdash$				$\vdash$	. 1	_		1	ノ、ႃŢ	г —			
	680	681	1																		'		1 1						
	1000	102																				`				_			
	1500	152	J	J	J	J	J	J	М														T			_			
	2200	222	J	J	J	J	J	J	М																	_			
	3300 4700	332 472	J	J	J	J	J	J	M M													-	$\vdash$		+-	+			
	6800	682	J	J	J	J	J	J	M																$\vdash$	<del></del>			
Сар	0.01	103	J	J	J	J	J	J	M		K	K	K	K	K	М	М	M		Х	Х	Х	Х	М	Р	Р			
(µF)	0.015	153	J	J	J	J	J	J	Р		K	K	K	К	Р	М	М	М		Х	Х	Х	Х	М	Р	Р			
	0.022	223	J	J	J	J	J	J	Q		K	K	K	K	Р	М	М	М		Х	Х	Х	Х	М	Р	Р			
	0.033	333	J	J	J	J	J	J	Q		K	K	K	K	Х	М	М	М		Х	Х	Х	Х	M	Р	Р			
	0.047	473	J	J	J	J	J	J	Q		K	K	K	K	Z	M	M	M		X	X	X	X	M	P	P			
-	0.058	683 104	J	J	J	J	J	M M	Q X		K K	K K	K	K	Z Z	M M	M	M M		X	X	X	X	M M	P	P			
-	0.15	154	J	J	J	J	M	Z	^		K	K	K	P	Z	M	M	M		X	X	X	X	M	P	X			
	0.22	224	J	J	J	J	P	Z			K	K	K	P	Z	M	M	M		X	X	X	X	M	P	X			
	0.33	334	J	J	J	J	Q				K	K	M	Х		М	М			Х	Х	Х	Х	М	Р	X			
	0.47	474	M	М	M	М	Q				K	K	Р	Х		M	M			X	Х	Х	Х	М	Р	X			
	0.68	684	M	M	P	X	X				M	М	Q			М	P			X	X			М	P	X			
	1.0	105 155	N N	N N	P Z	X Z	Z			<del>                                     </del>	M Z	M Z	X Z	Z		M Q	Р			X	X		$\vdash$	M M	P X	Z			
	2.2	225	X	X	Z	Z	Z				Z	Z	Z			Q				X	X		$\vdash$	M	X	Z			
	3.3	335	X	X	Z	Z	Z				Z	Z	Z							X	Z								
	4.7	475	Z	Z	Z	Z					Z	Z								Х	Z								
	10	106	Z	Z	Z	Z				Z										Z	Z				$\perp$				
	22	226	Z	Z	Z		-	_		<u> </u>			-						Z			-	$\vdash$		—				
	47 100	476 107	Z													-						-	$\vdash$		$\vdash$	+			
		NVDC	10	16	25	50	100	200	500	16	25	50	100	200	500	50	100	200	25	50	100	200	500	50	100	200			
SIZE			1.0	1210								1812						200		- 00	222		000		222				
												1812				1825							<u>'</u>			1			
-	Letter Max.		A 0.33	E	22	0.56		E 0.71	0	90	J 0.94		1.02	_	И 27	N P 1.40 1.52				Q .78	2.2		Y 2.54	+ :	1				
	Thickness		0.013)		009)	(0.022		(0.028)		35)	(0.037		(0.040)		050)		1.40 1.52 (0.055) (0.060)			.76	(0.09		(0.100)	(0					
						F	PAPER	2								EMBOSSED													

NOTE: Contact factory for non-specified capacitance values